

**実用的シミュレーションに向けた、第一原理計算手法の開発  
時間に依存する外場下での電子・格子ダイナミクス**

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第12回コンピュテーショナル・マテリアルズ・デザイン  
CMD®ワークショップ 2008年3月4日—3月8日

# outline

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1. Application of the Time-dependent density functional theory
2. Ion collision to solid surface (Fabrication & Analysis using ion-beam)
3. Time-varying dielectric field (Pulse laser, dynamical conductivity)

U can change.

1. Application of the Time-dependent density functional theory
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# 0. What's ab initio MD?

Molecular dynamics:

Electrons are under the ground  
(stationary) state  
Atoms follow Newton's classical  
dynamics

Thermodynamics, mechanics, reaction paths

$$H\psi_n = \epsilon_n \psi_n$$

$$-\frac{\partial V}{\partial R_I} = M_I \frac{\partial^2 R_I}{\partial t^2}$$

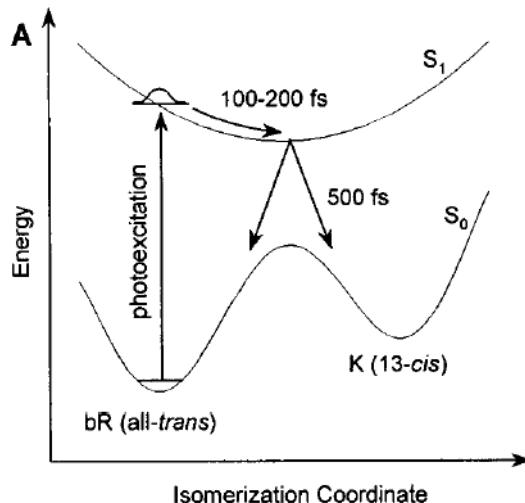
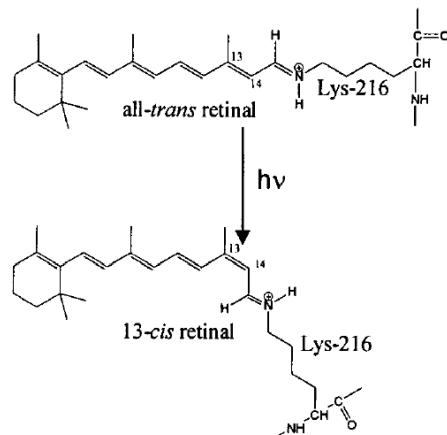
Adiabatic approximation is a  
proper approach.

# 1. What's excited state dynamics?

Molecular dynamics under electronic excitation

ex). Photo-chemical reaction, high-energy atom/ion impact

Lifetime of excited state compared to time for atomic motion is a key factor



We need to treat electron  
dynamics!

$$i\hbar \frac{\partial \psi_n}{\partial t} = H\psi_n$$

F. Gai et al. Science  
279, 1886 (1998)

# Time-dependent version of the Density Functional Theory

E. Runge and E. K. U. Gross, PRL, 52, 997(1984).

Instead of total energy minimization, minimize an action given as,

$$A = \int_{t_0}^{t_1} dt \langle \Phi(t) | i\partial/\partial t - \hat{H}(t) | \Phi(t) \rangle$$

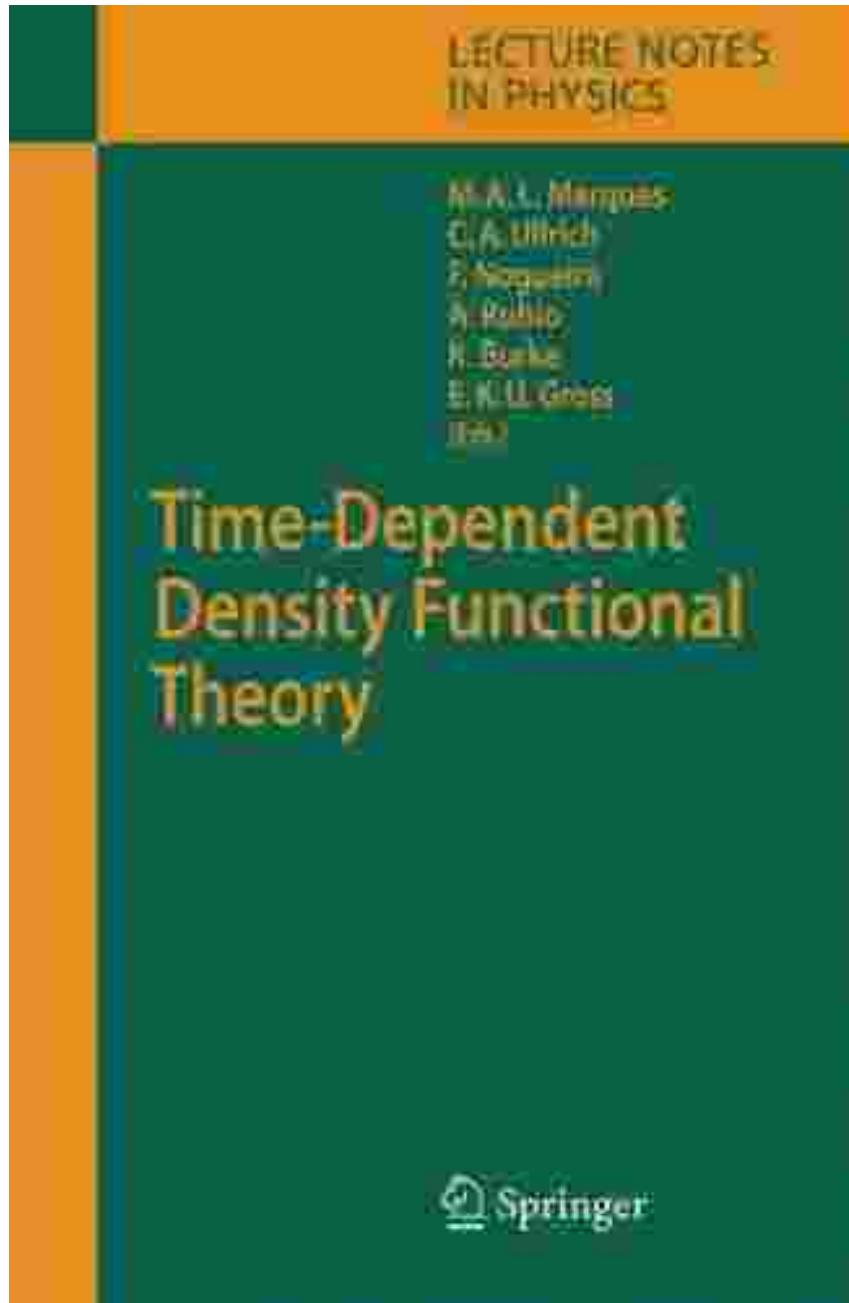
Within DFT  $\langle \phi | H | \phi \rangle = E_{\text{tot}} \rightarrow \delta A = 0$  gives

$$i\hbar \frac{d\psi_n(\vec{r}, t)}{dt}$$

$$= \left( -\nabla^2 + \int \frac{\rho(\vec{r}', t)}{|\vec{r} - \vec{r}'|} d\vec{r}' + \mu_{xc}[\rho(\vec{r}, t)] + \sum_I \tilde{v}(\vec{r}' - \vec{R}_I(t), \vec{r} - \vec{R}_I(t)) + \sum_I \frac{Z_I(\vec{R}_I)}{|\vec{r} - \vec{R}_I(t)|} \right) \psi_n(\vec{r}, t)$$

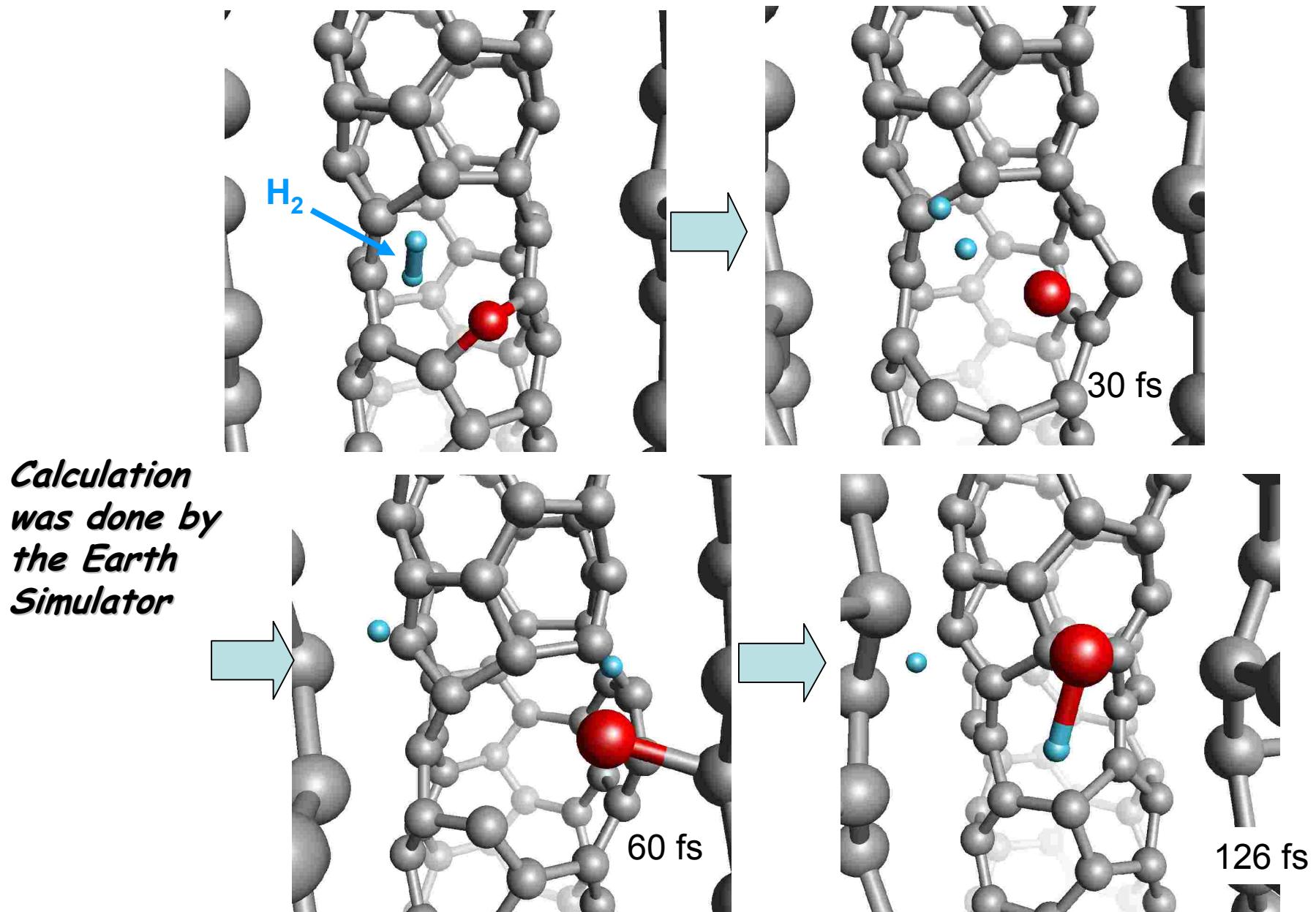
→ one-to-one relation with  $v(\vec{r}, t)$  and  $\rho(\vec{r}, t)$  with proper initial condition

## Time-dependent Kohn-Sham equation



80 €

# Spontaneous O emission from CNT by electronic excitation!



U can change.

# Excited state dynamics within TDDFT-MD (Sugino, Miyamoto 1999, PRB)

TDDFT: plane wave and pseudopotentials

Classical MD with Hellman-Feynman forces

$$i\hbar \frac{\partial \psi_n}{\partial t} = H\psi_n$$

$$-\frac{\partial V}{\partial R_I} = M_I \frac{\partial^2 R_I}{\partial t^2}$$

Use of Hellman-Feynman forces based on Ehrenfest's framework. But we must seriously think about potential energy surface for ions **at the moment of non-adiabatic transition.**

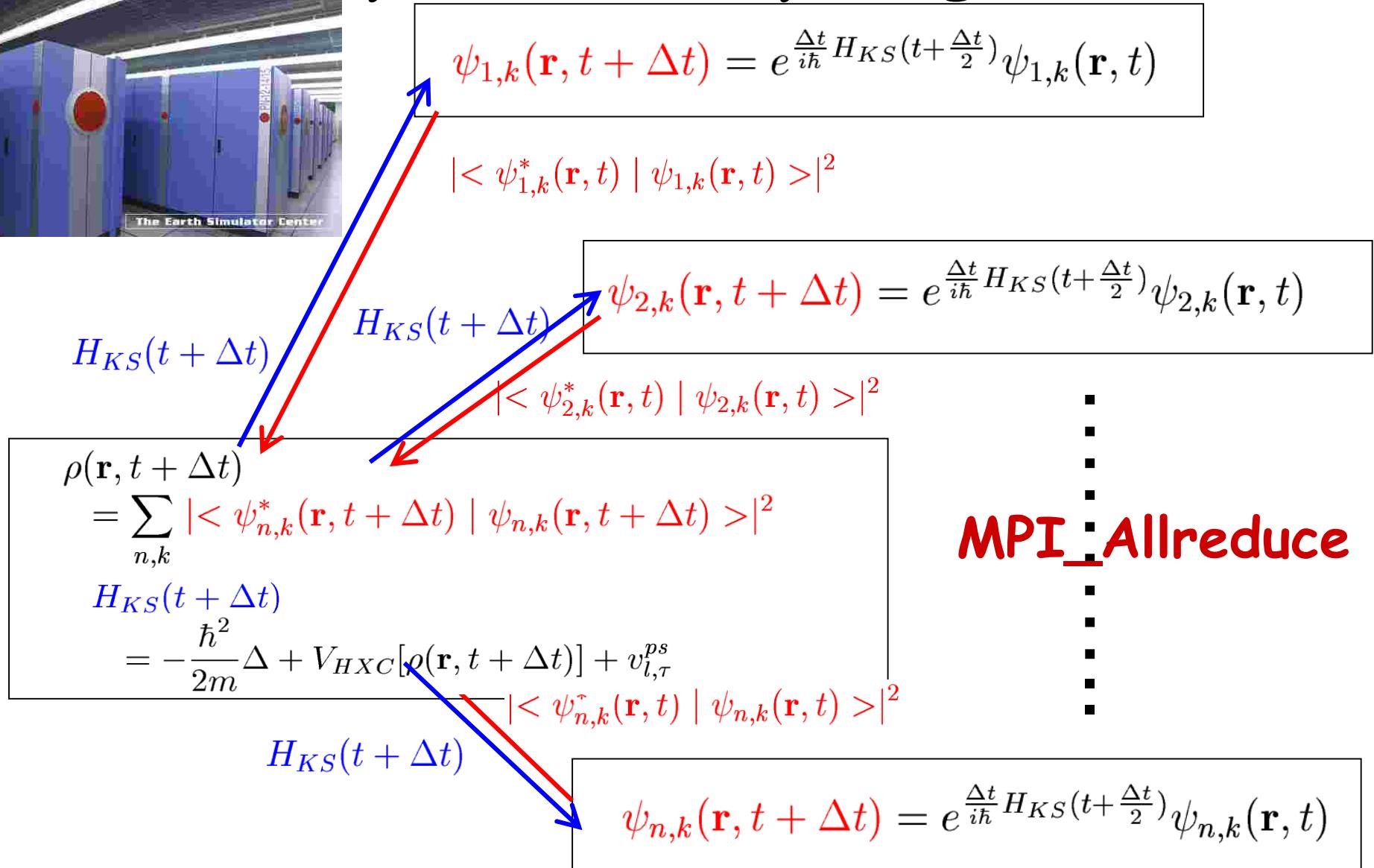
$$F_I^{HF} = -\int \rho(r) \frac{\partial \sum_I V_I(r - R_I)}{\partial R_I} - \sum \frac{\partial E_{ion-ion}}{\partial R_I}$$

$$- 2 \operatorname{Re} \sum_n f_n \sum_{\alpha, \beta} C_\alpha^n C_\beta^n \left\langle \frac{\partial \phi_\alpha}{\partial R_I} \mid H - \varepsilon_n \mid \phi_\beta \right\rangle$$

$$- 2 \operatorname{Re} \sum_n f_n \sum_{\alpha, \beta} \frac{\partial C_\alpha^n}{\partial R_I} C_\beta^n \left\langle \phi_\alpha \mid H - \varepsilon_n \mid \phi_\beta \right\rangle$$

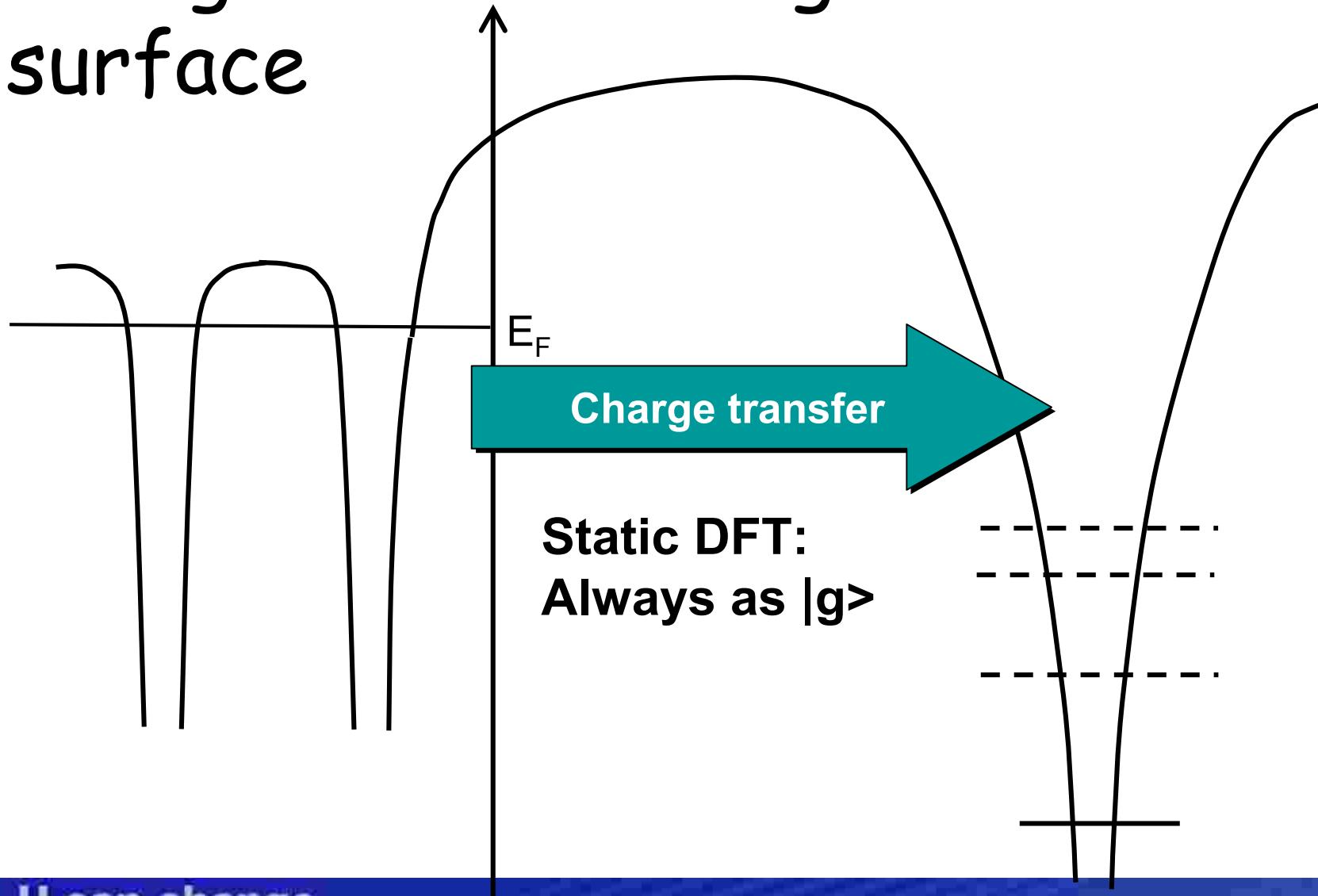
In case of TDDFT,  $\varepsilon_n$  is not the eigenvalue but expectation value.

# Thanks to parallel computing



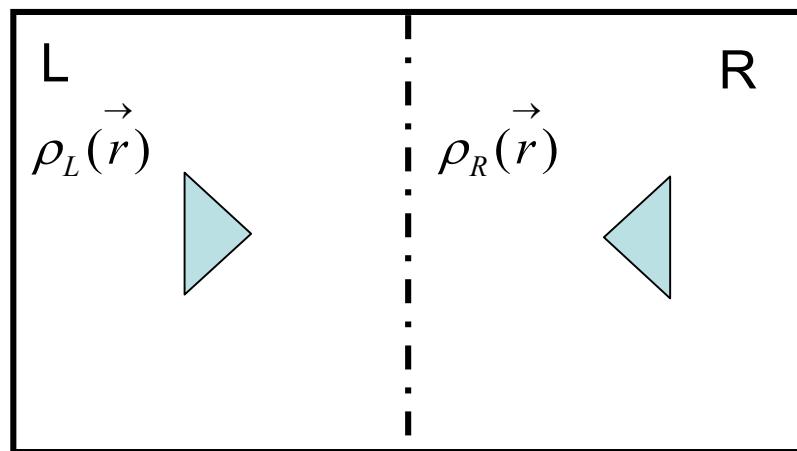
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# Simulating High-Speed Highly-Charged Ion colliding to a solid surface



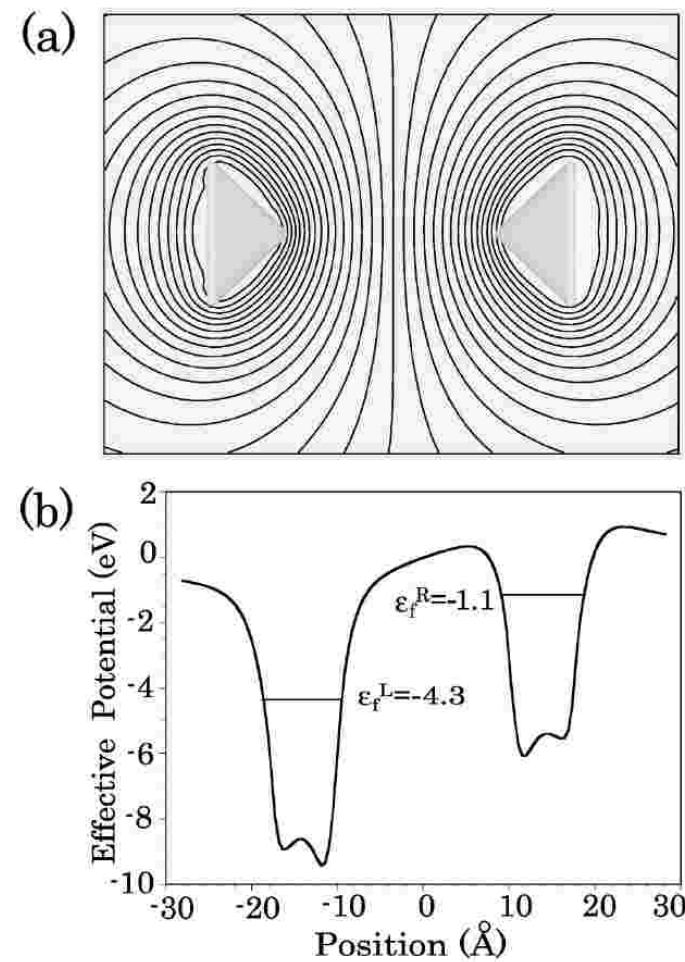
**Partitioned Real-Space Density Functional Calculations of Bielectrode Systems  
under Bias Voltage and Electric Field**

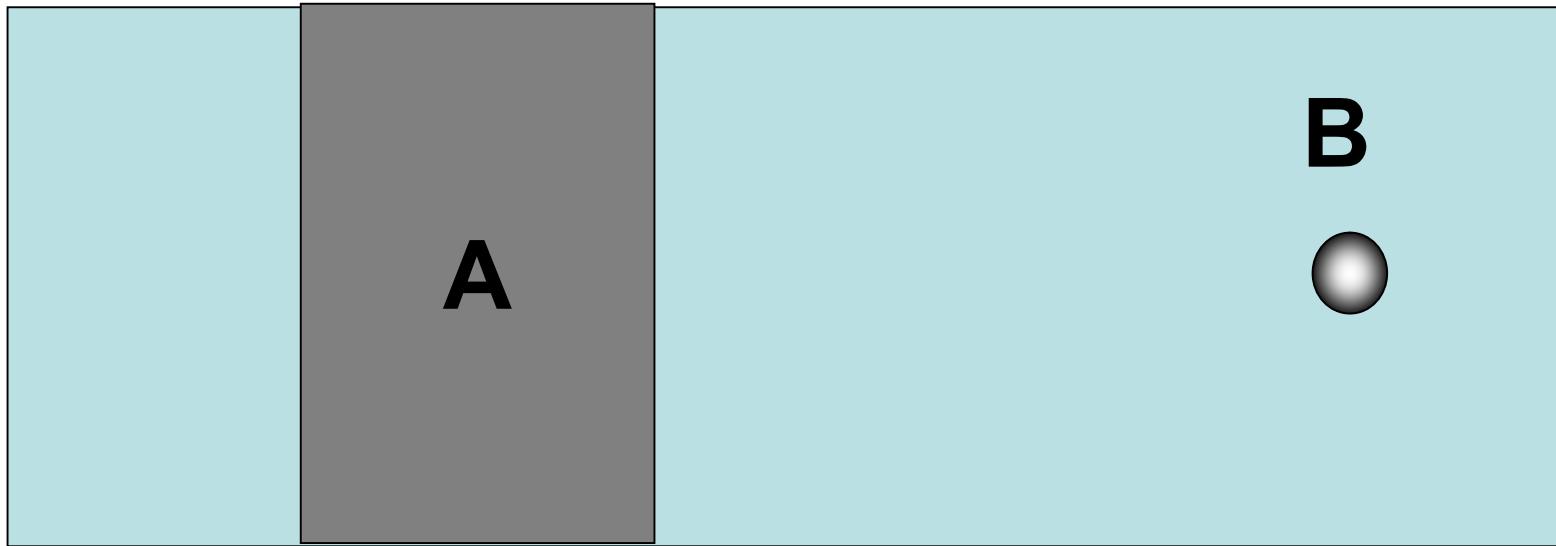
N. Nakaoka,<sup>1</sup> K. Tada,<sup>1</sup> S. Watanabe,<sup>3,5</sup> H. Fujita,<sup>4,5</sup> and K. Watanabe<sup>1,2,5</sup>



$$H_{KS}^L(\vec{r}) = -\frac{\hbar^2}{2m} \nabla^2 + V_H[\rho_L(\vec{r}) + \rho_R(\vec{r})] + V_{XC}[\rho_L(\vec{r})] + V_{ION}^L(\vec{r})$$

$$H_{KS}^R(\vec{r}) = -\frac{\hbar^2}{2m} \nabla^2 + V_H[\rho_L(\vec{r}) + \rho_R(\vec{r})] + V_{XC}[\rho_R(\vec{r})] + V_{ION}^R(\vec{r})$$





$t = 0$

$$\rho(r, t=0) = \rho_A(r) + \rho_B(r)$$

$$\{\psi_1(r, t=0), \psi_2(r, t=0), \dots, \psi_N(r, t=0)\}$$

$$= \{\psi_1^A(r), \psi_2^A(r), \dots, \psi_{N_A}^A(r), \psi_1^B(r), \psi_2^B(r), \dots, \psi_{N_B}^B(r)\}$$

$t > 0$

$$i\hbar \frac{d\vec{\psi}_n(\vec{r}, t)}{dt} = H[\vec{\rho}(\vec{r}, t)]\vec{\psi}_n(\vec{r}, t)$$

$$\vec{F}_I = M_I \frac{d\vec{R}_I}{dt}$$

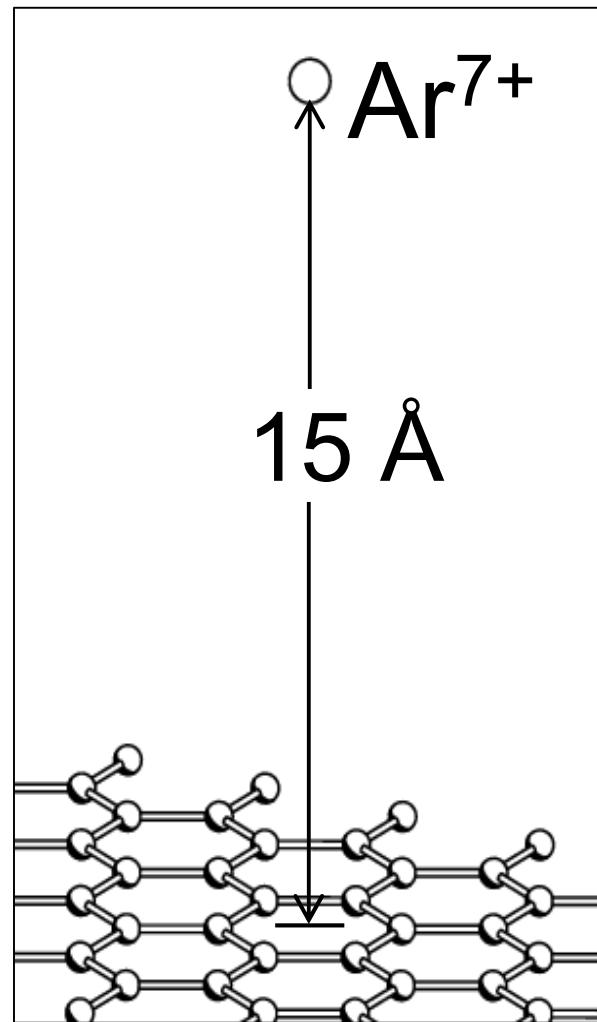
# Demonstration: Ar<sup>7+</sup> passing through a graphene sheet

Computational conditions (TDDFT-MD)

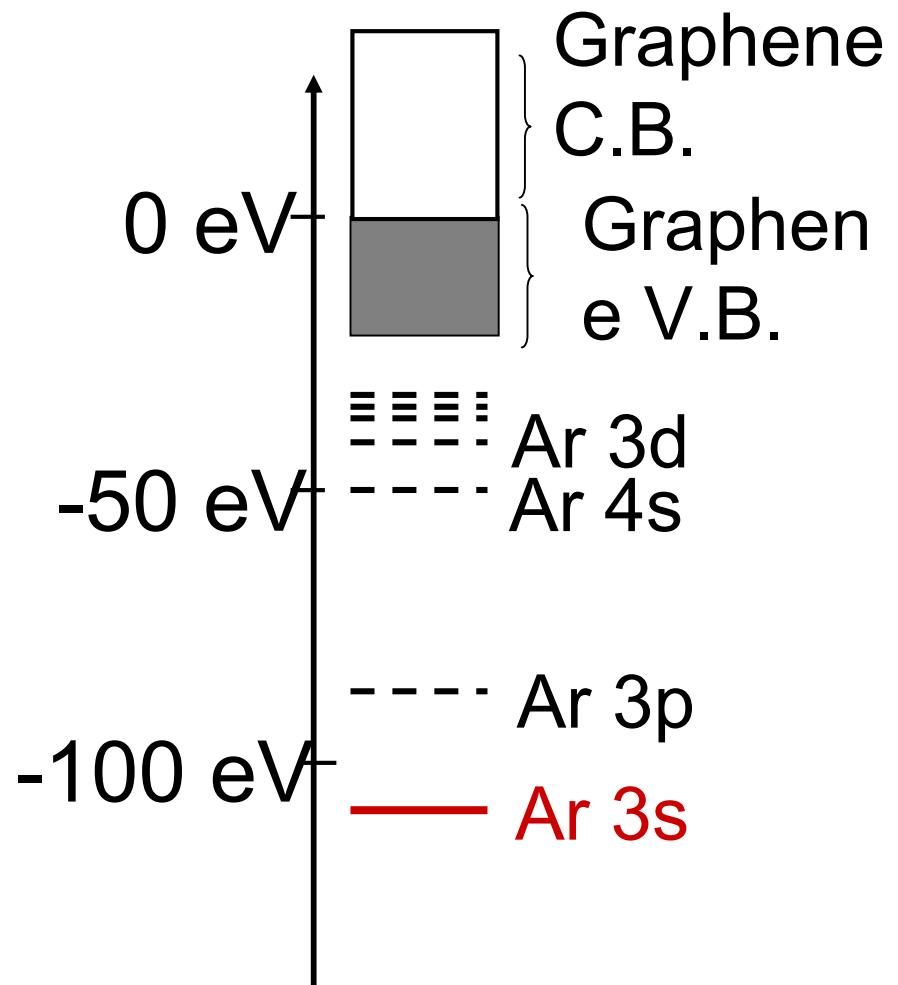
## Computational conditions

1. Plane wave basis set ( $E_{cut}=60\text{ Ry}$ )
2. Pseudo potentials (Troullier-Martins)
3.  $\Gamma$ -points with a  $5\times 5$  graphene layer (50 C atoms)
4. 30 Å for vacuum region
5.  $dt=0.02 \text{ a.u.} (4.84\times 10^{-4} \text{ fs})$

## Computational condition

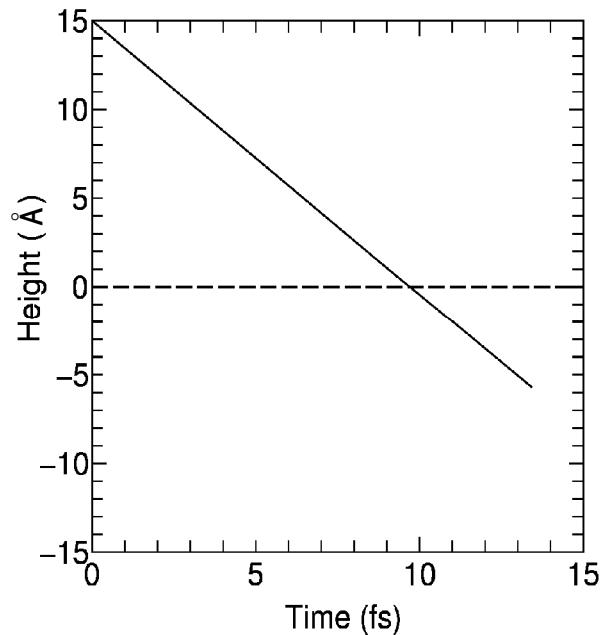


## Energy levels

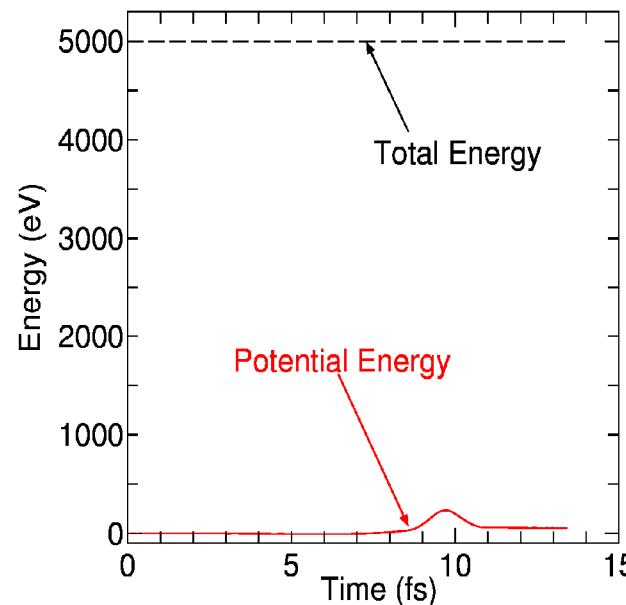


# $\text{Ar}^{7+}$ with incident energy of 5 KeV

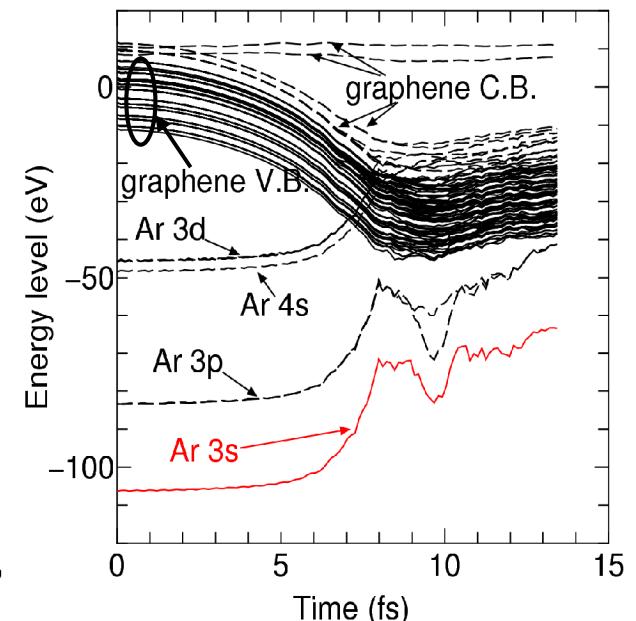
Position



Potential plus  
kinetic energy



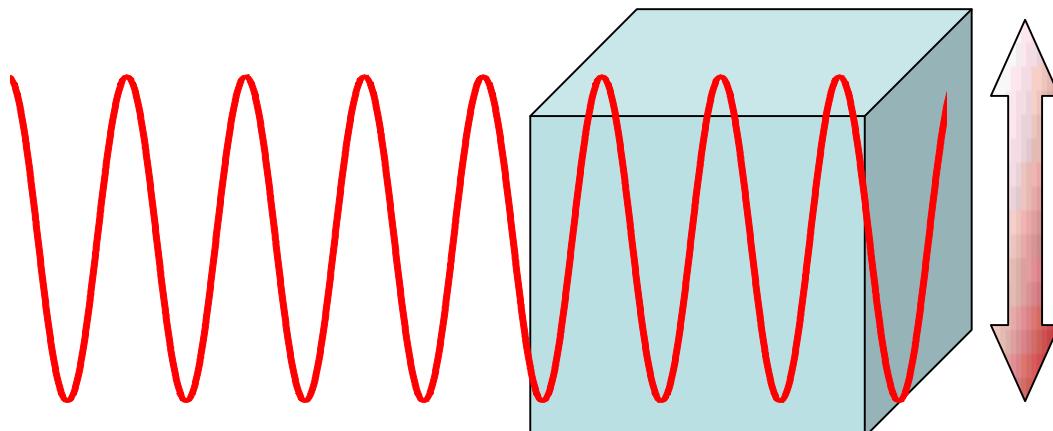
e-levels



Miyamoto, Zhang, PRB 77, 045433 (2008).

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# Pioneering works: 筑波大学 矢花先生

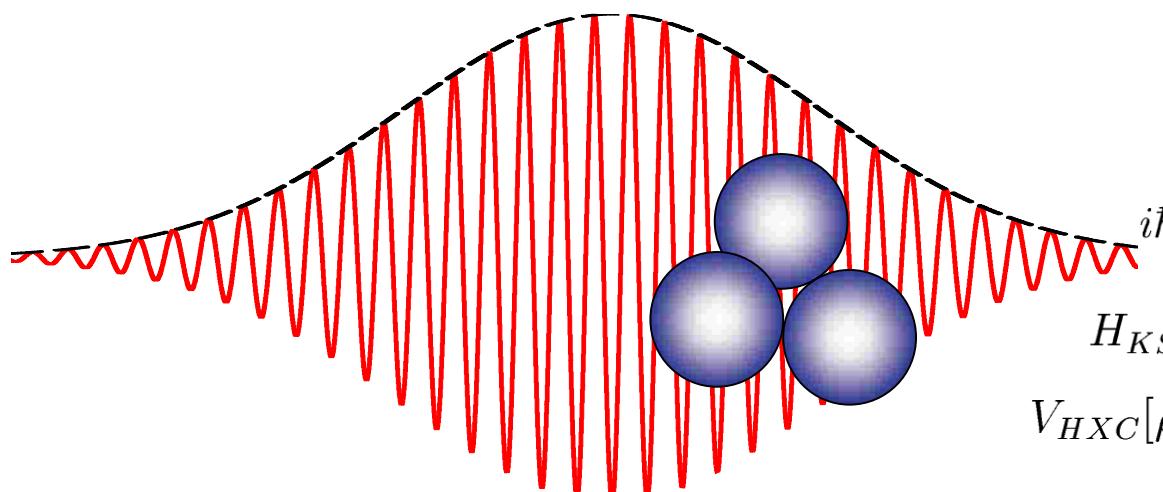


$$i\hbar \frac{d\psi_{n,k}(\mathbf{r}, t)}{dt} = H_{KS} [\rho(\mathbf{r}, t)] \psi_{n,k}(\mathbf{r}, t)$$

$$H_{KS} [\rho(\mathbf{r}, t)] \Rightarrow H_{KS} [\rho(\mathbf{r}, t), \mathbf{A}(t)]$$

$$-\frac{\hbar^2}{2m} \left( \mathbf{P} - \frac{1}{c} \mathbf{A}(t) \right)^2$$

Bertsch, et al., PRB62 7998, (2000).



$$i\hbar \frac{d\psi_{n,k}(\mathbf{r}, t)}{dt} = H_{KS} [\rho(\mathbf{r}, t)] \psi_{n,k}(\mathbf{r}, t)$$

$$H_{KS} [\rho(\mathbf{r}, t)] \Rightarrow H_{KS} [\rho(\mathbf{r}, t), V_{ext}(\mathbf{r}, t)]$$

$$V_{HXC}[\rho(\mathbf{r}, t)] \Rightarrow V_{HXC}[\rho(\mathbf{r}, t)] + V_{ext}(\mathbf{r}, t)$$

Castro et al., Eur. Phys. J. D 28, 211 (2004).

How can we know that the simulation goes numerically correct?

Let us use total-energy conservation rule.

In case of classical molecular dynamics (MD)

$$U(t) = \sum_I \frac{M_I}{2} \left( \frac{d\mathbf{R}_I}{dt} \right)^2 + V(\mathbf{R}_1(t), \mathbf{R}_2(t), \dots, \mathbf{R}_N(t))$$

$$\frac{dU(t)}{dt} = \sum_I \left( \frac{d\mathbf{R}_I(t)}{dt} \cdot M_I \frac{d^2\mathbf{R}_I(t)}{dt^2} + \frac{d\mathbf{R}_I(t)}{dt} \cdot \frac{\partial V(\mathbf{R}_1(t), \mathbf{R}_2(t), \dots, \mathbf{R}_N(t))}{\partial \mathbf{R}_I(t)} \right) = 0$$

because 
$$-\frac{\partial V(\mathbf{R}_1(t), \mathbf{R}_2(t), \dots, \mathbf{R}_N(t))}{\partial \mathbf{R}_I(t)} = M_I \frac{d^2\mathbf{R}_I(t)}{dt^2}$$

# In case of combination of MD and TDDFT

$V(\mathbf{R}_1(t), \mathbf{R}_2(t), \dots, \mathbf{R}_N(t)) \Rightarrow$

$$\sum_i \left( \int \psi_i^*(\mathbf{r}, t) \frac{-\hbar^2}{2m} \Delta \psi_i(\mathbf{r}, t) d\mathbf{r} + \int \int \psi_i^*(\mathbf{r}', t) v_{nl}(\mathbf{r}', \mathbf{r}) \psi_i(\mathbf{r}, t) d\mathbf{r}' d\mathbf{r} \right) + \frac{1}{2} \int \int \frac{\rho(\mathbf{r}', t) \rho(\mathbf{r}, t)}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' d\mathbf{r}$$

$$+ \int E_{XC}[\rho(\mathbf{r}, t)] d\mathbf{r} + \sum_I Z_I \left( \int \frac{\rho(\mathbf{r}, t)}{|\mathbf{R}_I(t) - \mathbf{r}|} d\mathbf{r} + \sum_{J \neq I} \frac{Z_J}{|\mathbf{R}_I(t) - \mathbf{R}_J(t)|} \right) \equiv E_{tot}^{DFT}(\mathbf{r}, t)$$

## MD simulation must conserve

$$U(t) = \sum_I \frac{M_I}{2} \left( \frac{d\mathbf{R}_I}{dt} \right)^2 + E_{tot}^{DFT}(\mathbf{r}, t)$$

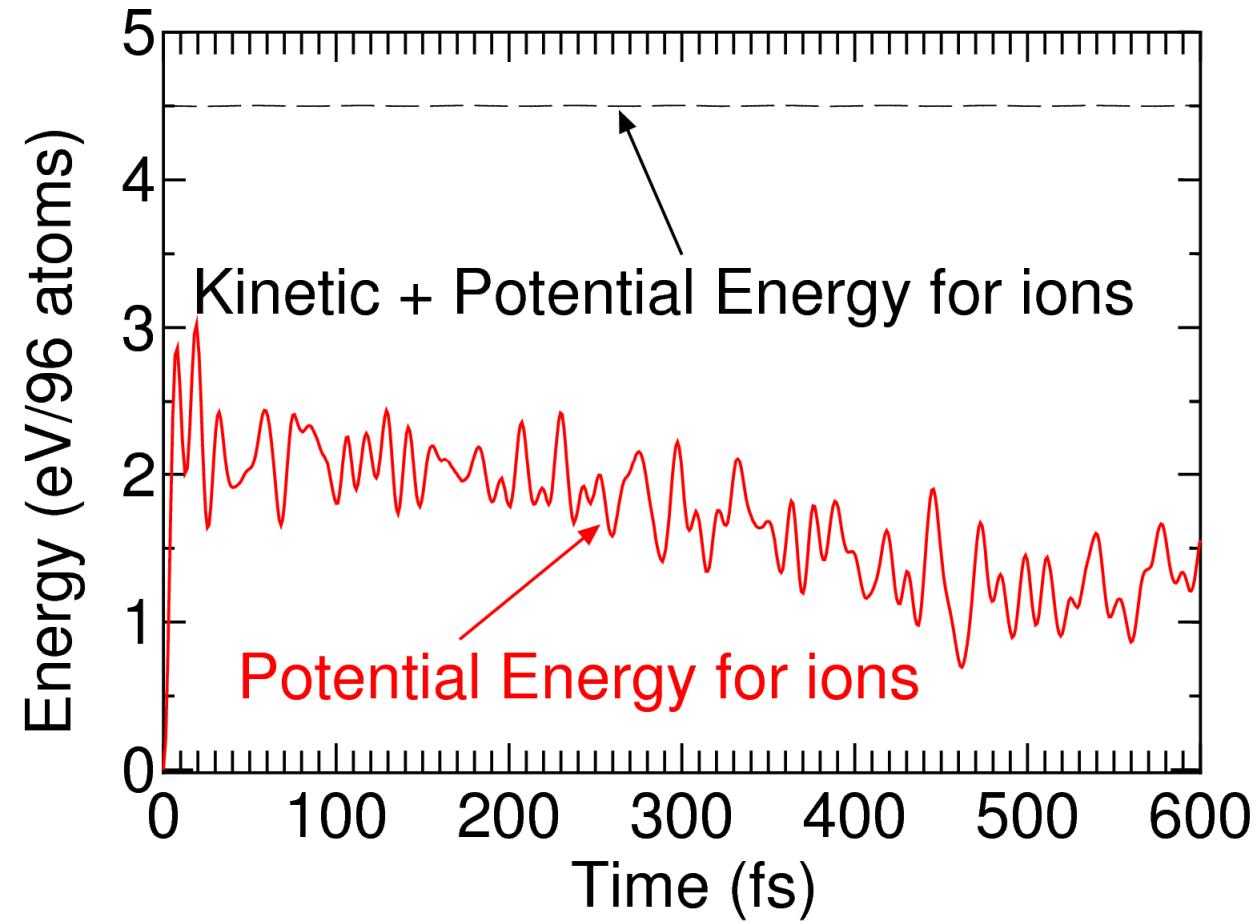
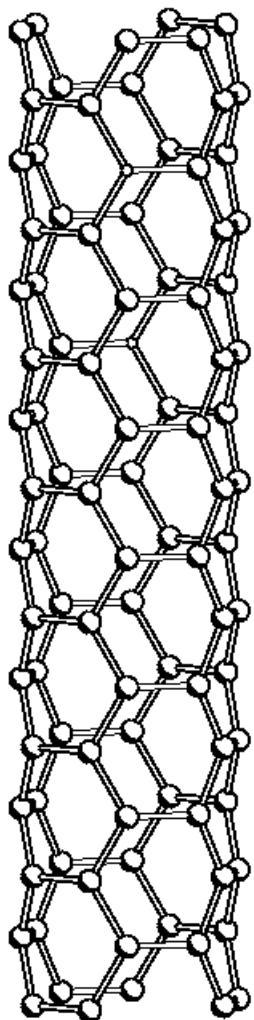
**TDDFT term**

$$\frac{dU(t)}{dt} = \sum_I \frac{d\mathbf{R}_I(t)}{dt} \cdot \left( M_I \frac{d^2\mathbf{R}_I(t)}{dt^2} + \frac{dE_{tot}^{KS}(\mathbf{r}, t)}{d\mathbf{R}_I(t)} \right) + \sum_i \left( \frac{d\psi_i^*(\mathbf{r}, t)}{dt} \frac{\delta E_{tot}^{DFT}(\mathbf{r}, t)}{\delta \psi_i^*(\mathbf{r}, t)} + C.C. \right)$$

$$M_I \frac{d^2\mathbf{R}_I(t)}{dt^2} = - \frac{dE_{tot}^{DFT}(\mathbf{r}, t)}{d\mathbf{R}_I(t)} = 0$$

$$\frac{\delta E_{tot}^{DFT}(\mathbf{r}, t)}{\delta \psi_i^*(\mathbf{r}, t)} = H_{KS}(\mathbf{r}, t) \psi_i(\mathbf{r}, t) = i\hbar \frac{d\psi_i(\mathbf{r}, t)}{dt}$$

## Example of TDDFT-MD 96 C atoms under R.T. and $173 \rightarrow 231$ excitation



# Without time-varying external field

$$\sum_i \left( \int \psi_i^*(\mathbf{r}, t) \frac{-\hbar^2}{2m} \Delta \psi_i(\mathbf{r}, t) d\mathbf{r} + \int \int \psi_i^*(\mathbf{r}', t) v_{nl}(\mathbf{r}', \mathbf{r}) \psi_i(\mathbf{r}, t) d\mathbf{r}' d\mathbf{r} \right) + \frac{1}{2} \int \int \frac{\rho(\mathbf{r}', t) \rho(\mathbf{r}, t)}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' d\mathbf{r}$$

$$+ \int E_{XC}[\rho(\mathbf{r}, t)] d\mathbf{r} + \sum_I Z_I \left( \int \frac{\rho(\mathbf{r}, t)}{|\mathbf{R}_I(t) - \mathbf{r}|} d\mathbf{r} + \sum_{J \neq I} \frac{Z_J}{|\mathbf{R}_I(t) - \mathbf{R}_J(t)|} \right) \equiv E_{tot}^{DFT}(\mathbf{r}, t)$$

# With time-varying external field

$$V_{ext}(\mathbf{r}, t) = \int \frac{\rho_{ext}(\mathbf{r}', t)}{|\mathbf{r}' - \mathbf{r}|} d\mathbf{r}'$$

$$E_{tot}^{DFT}(\mathbf{r}, t)$$

$$= \sum_i \left( \int \psi_i^*(\mathbf{r}, t) \frac{-\hbar^2}{2m} \Delta \psi_i(\mathbf{r}, t) d\mathbf{r} + \int \int \psi_i^*(\mathbf{r}', t) v_{nl}(\mathbf{r}', \mathbf{r}) \psi_i(\mathbf{r}, t) d\mathbf{r}' d\mathbf{r} \right) + \int E_{XC}[\rho(\mathbf{r}, t)] d\mathbf{r}$$

$$+ \frac{1}{2} \int \int \frac{(\rho(\mathbf{r}', t) + \rho_{ext}(\mathbf{r}', t)) (\rho(\mathbf{r}, t) + \rho_{ext}(\mathbf{r}, t))}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' d\mathbf{r}$$

$$+ \sum_I Z_I \left( \int \frac{(\rho(\mathbf{r}, t) + \rho_{ext}(\mathbf{r}, t))}{|\mathbf{R}_I(t) - \mathbf{r}|} d\mathbf{r} + \sum_{J \neq I} \frac{Z_J}{|\mathbf{R}_I(t) - \mathbf{R}_J(t)|} \right)$$

$$\begin{aligned}
E_{tot}^{DFT}(\mathbf{r}, t) &= \sum_i \left( \int \psi_i^*(\mathbf{r}, t) \frac{-\hbar^2}{2m} \Delta \psi_i(\mathbf{r}, t) d\mathbf{r} + \int \int \psi_i^*(\mathbf{r}', t) v_{nl}(\mathbf{r}', \mathbf{r}) \psi_i(\mathbf{r}, t) d\mathbf{r}' d\mathbf{r} \right) + \int E_{XC}[\rho(\mathbf{r}, t)] d\mathbf{r} \\
&\quad + \frac{1}{2} \int \int \frac{(\rho(\mathbf{r}', t) + \rho_{ext}(\mathbf{r}', t)) (\rho(\mathbf{r}, t) + \rho_{ext}(\mathbf{r}, t))}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' d\mathbf{r} \\
&\quad + \sum_I Z_I \left( \int \frac{(\rho(\mathbf{r}, t) + \rho_{ext}(\mathbf{r}, t))}{|\mathbf{R}_I(t) - \mathbf{r}|} d\mathbf{r} + \sum_{J \neq I} \frac{Z_J}{|\mathbf{R}_I(t) - \mathbf{R}_J(t)|} \right)
\end{aligned}$$


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$$\begin{aligned}
U(t) &= \sum_I \frac{M_I}{2} \left( \frac{d\mathbf{R}_I}{dt} \right)^2 + E_{tot}^{DFT}(\mathbf{r}, t) && \text{Goes to zero!} \\
\frac{dU(t)}{dt} &= \sum_I \frac{d\mathbf{R}_I(t)}{dt} \cdot \left( M_I \frac{d^2\mathbf{R}_I(t)}{dt^2} + \frac{dE_{tot}^{KS}(\mathbf{r}, t)}{d\mathbf{R}_I(t)} \right) + \sum_i \left( \frac{d\psi_i^*(\mathbf{r}, t)}{dt} \frac{\delta E_{tot}^{DFT}(\mathbf{r}, t)}{\delta \psi_i^*(\mathbf{r}, t)} + C.C. \right) \\
&\quad + \int \frac{d\rho_{ext}(\mathbf{r}, t)}{dt} \int \left( \frac{(\rho(\mathbf{r}', t) + \rho_{ext}(\mathbf{r}', t))}{|\mathbf{r}' - \mathbf{r}|} d\mathbf{r}' + \sum_I Z_I \frac{1}{|\mathbf{R}_I(t) - \mathbf{r}|} \right) d\mathbf{r} && \text{Remains as non-zero!}
\end{aligned}$$

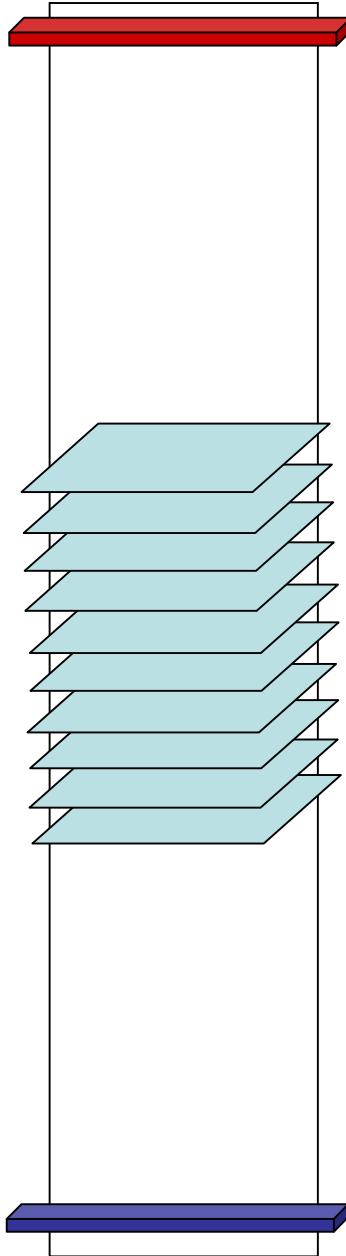
Work by external field is

$$W(t) = \int_{t_0}^t \frac{dU(t')}{dt'} dt' + W(t = t_0)$$

Thus a new conservation rule is

$$\frac{d(U(t) - W(t))}{dt} = 0$$

Miyamoto, Zhang, submitted



+ Fictitious charge (+)

10-layer  
graphite

- Fictitious charge (-)

## Test calculation:

- AB-stacked graphite  
2x2 cell in lateral  
directions
- under pulse E-field
- $E_{cut}=60$  Ry
- TM type  
pseudopotentials
- Single k-point
- $dt=1.84 \times 10^{-4}$  fs

Conservation rule was  
numerically confirmed

# sumaries

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1. Time-dependent density functional approach as a practical tool for nano-engineering
2. Ion-surface interaction
3. Irradiation with pulse shot

**Some applications will be presented**